VS-VSKCS201/045

Vishay Semiconductors





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PRODUCT SUMMARY				
I _{F(AV)}	200 A			
V _R	45 V			
Package	ADD-A-PAK			
Circuit	Two diodes common cathodes			

MECHANICAL DESCRIPTION

The ADD-A-PAK generation VII, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation
- Low thermal resistance
- UL approved file E78996
- · Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- Easy mounting on heatsink

ELECTRICAL DESCRIPTION

The VS-VSKCS201.. Schottky rectifier common cathode has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	200	А		
V _{RRM}		45	V		
I _{FSM}	t _p = 5 μs sine	8600	А		
V _F	100 A _{pk} , T _J = 125 °C	0.69	V		
TJ	Range	- 55 to 175	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-VSKCS201/045	UNITS		
Maximum DC reverse voltage	V _R	45	V		
Maximum working peak reverse voltage	V _{RWM}	45	v		



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ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average per module			50 % duty cycle at T_{C} = 123 °C, rectangular waveform		200	
forward current	per leg	I _{F(AV)}	30% unity cycle at $T_C = 123\%$ C, rectangular wavelonn		100	1
Maximum peak one cycle		1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	8600	A
non-repetitive surge current		I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V_{RRM} applied	1850	
Non-repetitive avalanche energy		E _{AS}	T _J = 25 °C, I _{AS} = 24 A, L = 1 mH		270	mJ
Repetitive avalanche current		I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		20	А

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
		100 A	T _J = 25 °C	0.72	V
Maximum forward voltage drop	V _{FM}	200 A		1.04	
Maximum forward voltage drop		100 A	- T _J = 125 °C	0.69	
		200 A		0.98	
	I _{RM}	T _J = 25 °C	V _R = Rated V _R	10	mA
Maximum reverse leakage current		T _J = 125 °C		90	
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal rang	e 100 kHz to 1 MHz), 25 °C	5200	pF
Typical series inductance L _S		Measured lead to lead 5 mm from package body		7.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs
Maximum RMS insulation voltage	V _{INS}	50 Hz		3000 (1 min) 3600 (1 s)	V

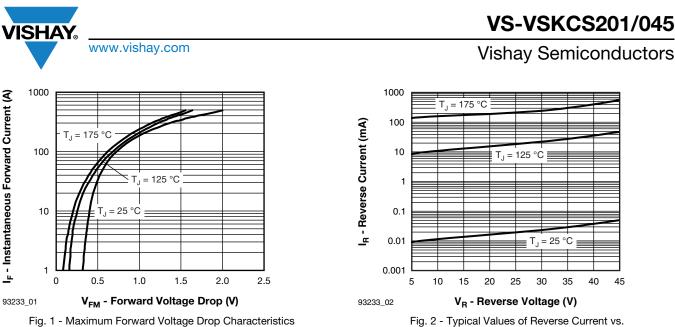
THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range)	T _J , T _{Stg}		- 55 to 175	°C
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	0.52	°C/W
Typical thermal resistance, case to heatsink per module		R _{thCS}		0.1	0/10
Approximate weight				75	g
				2.7	oz.
Mounting torque ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for	4	Nm
	busbar		the spread of the compound.	3	
Case style			JEDEC	TO-240AA co	mpatible

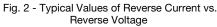
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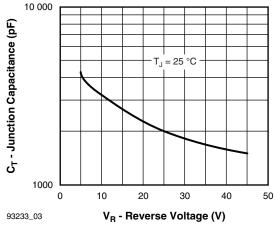
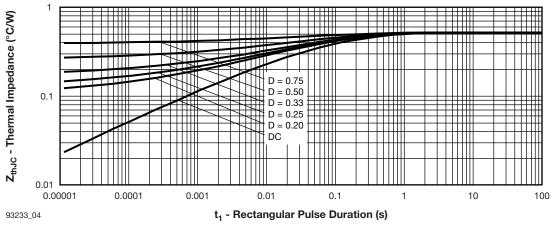
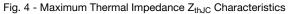


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





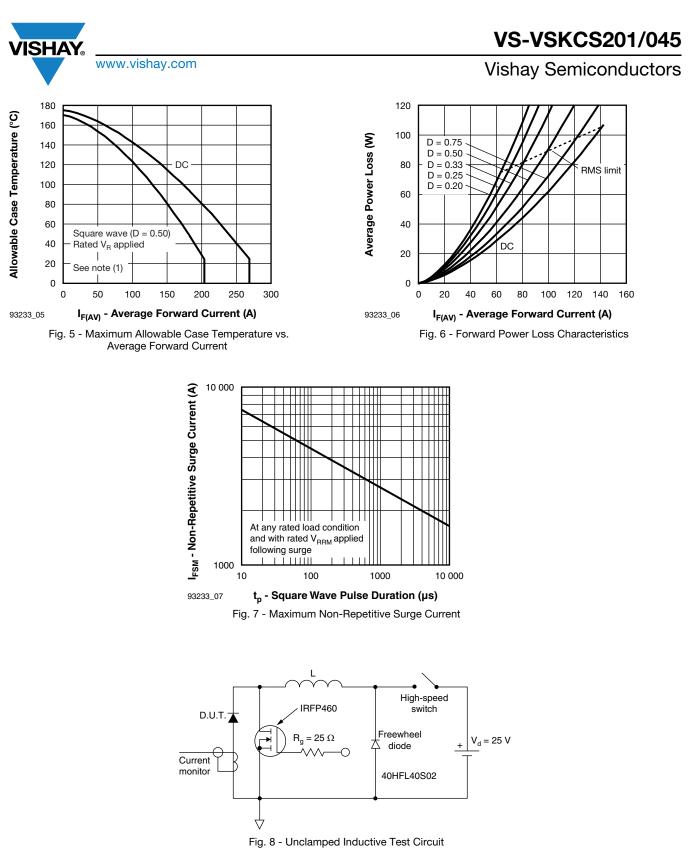
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I_F - Instantaneous Forward Current (A)

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Note

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \ - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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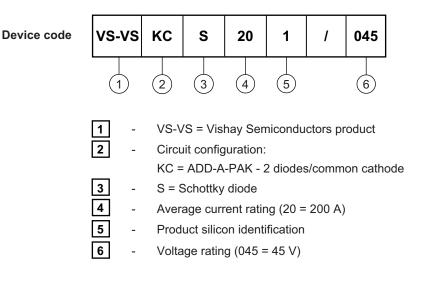
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⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC};$

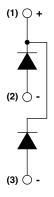
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ORDERING INFORMATION TABLE



CIRCUIT CONFIGURATION



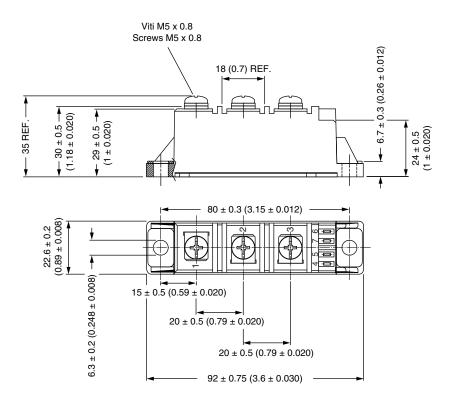
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95369			
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ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





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